

750 - 830 nm
830 - 920 nm
920 - 1100 nm
1100 - 1300 nm
1300 - 1450 nm
1450 - 1650 nm
1650 - 1850 nm
1850 - 1900 nm
1900 - 2200 nm
2200 - 2600 nm
2600 - 2900 nm

DFB laser diodes from 920 nm to 1100 nm

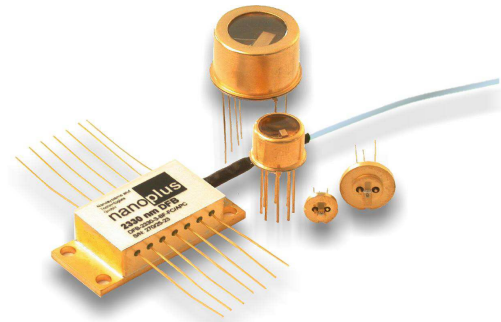
nanoplus single mode laser diodes

nanoplus is the only manufacturer world-wide routinely providing single mode laser diodes at any wavelength from 750 nm to 2900 nm. Our patented distributed feedback laser diodes deliver single mode emission with well defined optical properties enabling a wide range of applications. At wavelengths from 7 to 12 μm , nanoplus manufactures quantum cascade lasers.

nanoplus lasers operate reliably in more than 5000 installations worldwide, including chemical and metallurgical industries, gas pipelines, power plants, medical systems, airborne and satellite applications.

key features

- ✓ very high spectral purity
- ✓ narrow linewidth typically < 3 MHz
- ✓ excellent reliability
- ✓ wide variety of packaging options
- ✓ customer-specific designs available



application areas

- ✓ high performance gas sensing for process and environmental control
- ✓ precision metrology
- ✓ atomic clocks
- ✓ spectroscopy
- ✓ space technology

nanoplus lasers with excellent performance are specifically designed and characterized to fit your needs. This data sheet summarizes typical properties of nanoplus DFB lasers in the 920 to 1100 nm range. Overleaf data for lasers used for injection seeding of Nd:YAG lasers is given as an example. These lasers have applications in e.g. remote sensing of wind speeds, profiling of atmospheric molecules and aerosols and topographic mapping.

general ratings (T = 25 °C)	symbol	unit	typical
optical output power	P_{out}	mW	20
reverse Voltage	V_r	V	2
forward Current	I_f	mA	50
side mode suppression ratio (SMSR)		dB	> 35

On request, lasers with specifically optimized properties, e.g. higher output power, are available.

laser packaging options
TO5.6 header with or without cap
TO9 header with or without cap
TO5 with TEC and NTC
butterfly housing with FC/APC fibre

For dimensions and accessories, please see www.nanoplus.com
 Further packaging options available on request.

device protected by
 US patent 6.671.306
 US patent 6.846.689
 EU patent EP0984535

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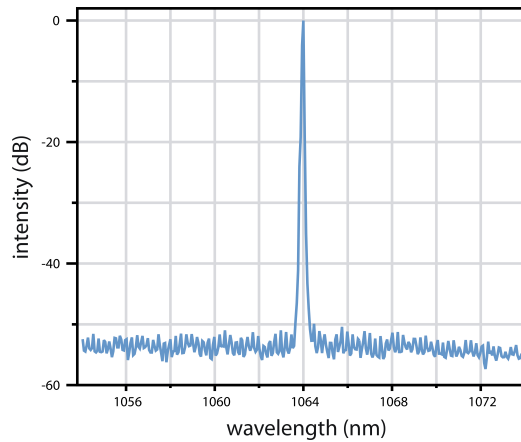
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nanoplus DFB laser diodes at 1064 nm

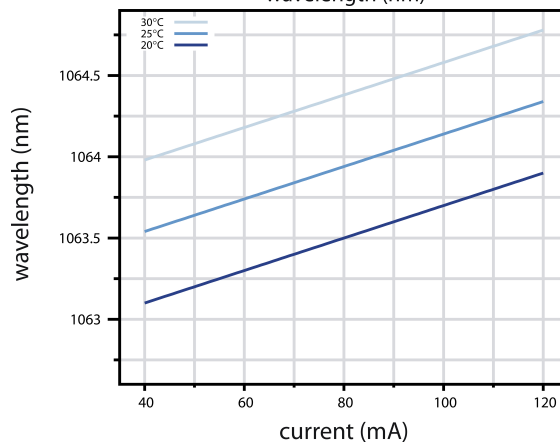
A wide variety of gas molecules, defects in solids etc. exhibit characteristic absorption lines in the near infrared. The wavelength of the main Nd:YAG laser transition is at 1064 nm. The 1064 nm DFB laser diodes are used for injection seeding of Nd:YAG lasers, which have applications in remote sensing of wind speeds, profiling of atmospheric molecules and aerosols and topographical mapping. Applications of this type rely on Nd:YAG lasers, which are seeded with highly stable laterally and longitudinally single mode lasers. This data sheet reports performance data of nanoplus DFB lasers at this wavelength. Similar performance data are obtained in the entire wavelength range from 920 nm to 1100 nm. For examples of performance data of nanoplus lasers in other wavelength ranges, please see www.nanoplus.com or contact sales@nanoplus.com.

Fig. 1
 Room temperature cw spectrum of a nanoplus DFB laser diode operating at 1064 nm



In many applications, temperature and/or current variations are used to adjust the laser emission precisely to the target wavelength.

Fig. 2
 Mode hop free tuning of 1064 nm based DFBs by current variation at different temperatures



electrooptical characteristics (T = 25 °C)	symbol	unit	min	typ	max
peak wavelength	λ	nm	1063	1064	1065
threshold current	I_{th}	mA	15	20	25
slope efficiency	e	mW / mA	0.35	0.4	0.5
temperature tuning coefficient	C_T	nm / K	0.07	0.08	0.09
current tuning coefficient	C_I	nm / mA	0.015	0.02	0.025
slow axis (FWHM)		degrees	12	15	20
fast axis (FWHM)		degrees	35	40	45
emitting area	W x H	$\mu\text{m} \times \mu\text{m}$	2.3 x 1.4	2.5 x 1.5	2.5 x 1.7
storage temperatures	T_S	°C	-40	20	80
operational temperature at case	T_c	°C	-20	25	50

We will be happy to answer further questions. Please contact us at sales@nanoplus.com

